

IRFBE30S

lest a Quote

IRFBE30S Information

www.hersener.com	Part Number	IRFBE30S	
	Manufacturer	Vishay Siliconix	
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	k
	Description	MOSFET N-CH 800V 4.1A D2PAK	. J
	Package	TO-263-3, D2Pak (2 Leads + Tab), TO-263AB	
		For the pricing/inventory/lead time, please contact	
		us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	R

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IRFBE30S Specifications

Manufacturer Part Number	IRFBE30S
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-263-3, D2Pak (2 Leads + Tab), TO-263AB
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	800V
Current - Continuous Drain (Id) @ 25°C	4.1A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	78nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1300pF @ 25V
Vgs (Max)	$\pm 20\mathrm{V}$
FET Feature	-
Power Dissipation (Max)	125W (Tc)
Rds On (Max) @ Id, Vgs	3 Ohm @ 2.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	D2PAK
Package / Case	TO-263-3, D2Pak (2 Leads + Tab), TO-263AB
	Report errors

IRFBE30S Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

If you have any question about IRFBE30S, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com